# A M ean-eld Calculation for the Three-D im ensional H olstein M odel<sup>1</sup>

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#### A bstract

A path integral representation appropriate for further M onte C arlo simulations is derived for the electron-phonon H olstein m odel in three spatial dimensions. The m odel is studied within m ean-eld theory. C harge density wave and superconducting phase transitions are discussed.

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## 1 Introduction

The B aP b<sub>1 x</sub> B i<sub>x</sub>O<sub>3</sub> alloys [1] are notable ancestors to the high temperature superconducting cuprates [2,3]. These compounds exhibit superconductivity in the Pb-rich composition range 0.05 x 0.3, with a maximum T 13K near x 0.25. A metal-sem iconductor transition is observed at x 0.35, with the sem iconducting behavior continuing to the end-member compound B aB iO<sub>3</sub> [1].

By substitutional K doping at the A (Ba) site,  $Ba_xK_{1x}BiO_3$  [4] has been found to exhibit superconductivity with  $T_c$  30K. Band-structure calcula-

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tions [4,5] indicate that the conduction bands in both materials consist of -antibonding combinations of (Pb,K)-Bi(6s) and O (2p) states. These bands are gradually lled in rigid-band fashion with increasing x until they are half lled in B aB iO<sub>3</sub>. Here, a combination of Ferm i-surface nesting and the strong coupling of the conduction-band states near  $E_F$  to bond-stretching O displacements leads to a commensurate charge-density-wave (CDW) order, thereby opening a sem iconducting gap at  $E_F$ , explaining the sem iconducting behavior of B aB iO<sub>3</sub>. The conduction bands may be well represented by simple tight-banding models. In contrast to the cuprate high temperature super-conductors, these materials are three-dimensional and copper-free, rendering magnetic mechanisms inapplicable. Furtherm ore, conduction electrons couple strongly to breathing type oxygen phonons over a wide composition range.

It appears to us from this picture that the three-dimensional Holstein Ham iltonian on a cubic lattice m ight constitute a m icroscopic model for these materials. The Holstein Ham iltonian is:

$$H = t X (c_x^y c_y + c_y^y c_x) + X (c_x^y + c_y^y c_x) = X (c_x^y + c_y^y c_x) + X (c_x^y + c_x^y + c_x^y c_x) = X (c_x^y + c_x^y + c_x^y c_x) + X (c_x^y + c_x^y + c_x^y c_x) = X (c_x^y + c_x^y + c_x^y c_x) + X (c_x^y + c_x^y + c_x^y c_x) = X (c_x^y + c_x^y + c_x^y c_x) + X (c_x^y + c_x^y + c_x^y c_x) = X (c_x^y + c_x^y c_x) + X (c_x^y + c_x^y c_x) = X (c_x^y +$$

Here,  $c_x^{\vee}$  creates an electron of spin at site x, and  $b_x^{\vee}$  is the creation operator for a local phonon mode of bare frequency  $!_0$  located at site x. The electrons have a one-electron overlap t between near-neighbor sites on a cubic lattice, is the chemical potential and g is the electron-phonon coupling constant.

For g = 0, the free electrons in the three-dimensional Holstein model have a tight binding band structure:  $(k) = 2t(\cos k + \cos k_2 + \cos k_3)$ . It has perfect nesting only at half-lling. As noted above, this band structure describes  $B \ aP \ b_1 \ x \ B \ i_x O_3$  and  $B \ a_x \ K_1 \ x \ B \ iO_3$  quite well. The Einstein phonon in the Holstein model corresponds to the oxygen breathing mode phonon in realm aterials. When x increases, the rigid-band fashion lling of B  $aP \ b_1 \ x \ B \ i_x O_3$  and  $B \ a_x \ K_1 \ x \ B \ iO_3$  corresponds to the variation of the deem ical potential in the Holstein model which determ ines band lling. All these features indicate the connections between the Holstein model could also represent an "exciton", a "plasm on", or any other interm ediate bosons. The Holstein m odel therefore has a wider range of applicabilities.

The idea that a single H am iltonian (1) describes both the sem iconducting and superconducting phases of B aP  $b_{1 x}$  B  $i_x$ O<sub>3</sub> and B  $a_x$ K  $_{1 x}$  B iO<sub>3</sub> is very appealing. The basic electron-electron interaction arising from the exchange of phonons is given by

$$V(i!_m) = \frac{2g^2!_0}{!_m^2 + !_0^2}$$
(2)

with  $!_m = 2m$  T. In the limit  $!_0=t$  1 with  $g^2=!_0$  nite, the Holstein model goes over to a negative-U Hubbard model with an electrive U equal to  $2g^2=!_0$  [6]. W hereas the basic electron-electron interaction in a Hubbard model is instantaneous and local, as is characterized by a constant U, that in the Holstein model is retarded, i.e., V (i!\_m) depends on frequency (see Eq. (2)). This retardation electron is portant role in subsequent discussions.

W hile reports on investigations for the three-dimensional Holstein model have been rare, the two-dimensional Holstein model has been previously investigated by a num ber of techniques, including quantum M onte C arlo simulations [6]. Som e of the conclusions from these studies are expected to hold in three dimensions. A coording to these studies, two competing types of correlations exist in the Holstein model, s-wave superconducting and Peierls CDW . At and near half-lling, CDW long range order prevails, further away from halflling, s-wave superconductivity dom inates. As ! 0=t increases, the boundary separating CDW and superconducting phases moves toward half-lling. In the negative U Hubbard model, which is a limiting case of the Holstein model, CDW can only be stabilized at half-lling. It is interesting to note that as ! \_= t is reduced and retardation becomes in portant, a region of lling around the half-led band is dominated by CDW correlations. It is reasonable to assume that a CDW phase is insulating. We thus expect that, unlike the Hubbard model, an insulating (sem iconducting) phase can be stabilized away from half-lling due to retardation in the Holstein model.

As pointed out by M attheiss and H am ann [5], the mechanism by which the sem iconducting properties of B aP  $b_{1 \times} B i_x O_3$  and B  $a_x K_{1 \times} B iO_3$  are extended over intermediate range of compositions is less well understood. The sem i-conducting behavior at half-lling, i.e., B aB iO<sub>3</sub>, may be understood from a combination of Ferm i-surface nesting and strong coupling to breathing mode oxygen phonons. Both ingredients are necessary to open a sem iconductor gap at the Ferm i surface. The gap should disappear quickly with the loss of Ferm i surface nesting away from hall-lling. W eber [7] proposed that this sem iconducting behavior was due to a combination of static incom mensurate \breathing-type" charge density waves and chem ical \ordering waves" on the Pb-B i sublattice. This mechanism , however, has som e di culties with band-structure calculations and perturbative arguments [5].

It thus appears from these discussions that retardation in the Holstein model m ight be responsible for the stabilization of the sem iconducting behavior away from half-lling. B  $a_x K_{1x}$  B iO<sub>3</sub> sim ply has a phonon frequency higher than that of B aP  $b_{1x}$  B  $i_x$ O<sub>3</sub>. Consequently, the metallic regime of these alloys is extended closer to half-lling, where the deform ation potentials for breathing-type O displacements and the electron-phonon interaction are at maximum, thus resulting in a higher  $T_c$ . As superconductivity occurs near a CDW transition, the coherence length is expected to be short, in agreement with exper-

im ental observations.

Several previous studies [8,9] have used certain types of negative-U Hubbard m odels to describe B aP  $b_{1 \times}$  B  $i_{x}O_{3}$  system s. The CDW s in Hubbard and Holstein m odels di er in one respect. CDW in the form er is complete in the sense that alternating lattice sites are doubly occupied and empty; while in the latter, charge is only partly transferred with an amount set by retardation. Infrared [11] and x-ray-photoem ission-spectroscopy [12] m easurem ents suggest only m arginal di erences in the charge distributions at the B isites [5], lending further support to the Holstein m odel description of these m aterials.

Sym m etry argum ents [10] can be used to classify electronic phase transitions in the three-dimensional Holstein model. At half-lling, superconducting and CDW channels are degenerate. In this case the two-component superconducting order parameter (complex scalar) and the one-component CDW order parameter (real scalar) may be considered jointly as a three-component vector order parameter. Away from half-lling the degeneracy between the superconducting and CDW phases is broken. Thus phase transitions of CDW at halflling, away from half-lling, and superconductivity belong to the universality classes of the three-dimensional Heisenberg, Ising, and XY models respectively. The corresponding phase transitions in B aP  $b_{1 \times}$  B  $i_x$ O<sub>3</sub> and B  $a_x$ K  $_{1 \times}$  B  $iO_3$  are thus identified. It will be interesting to explore consequences of this classic cation in these system s.

## 2 Path integral representation of the model

To obtain a path integral representation for the (grand) canonical partition function = T r exp[ H ], one rst expresses the bosonic creation and annihilation operators in terms of a bosonic eld  $_x$  and the corresponding conjugate momenta  $_x$  de ned as:

$$b_x = \frac{r}{2} \frac{1}{2} + \frac{1}{2} \frac{x}{2} + \frac{1}$$

It is easy to see that x and x de ned above satisfy the usual commutation relations:  $[x; y] = i_{xy}$ . The Ham iltonian of the model now becomes:

$$H = t X_{x; i} C_{x}^{y} (c_{x+\wedge} + c_{x \wedge}) X_{x} p \overline{2!_{0}}_{x} + p_{x}$$
  
+ 
$$X_{x} \frac{2}{2} + \frac{12}{2} 2^{2} x = 1$$
 (4)

The inverse temperature 1=T is then divided into  $N_t$  slices in the \temporal" direction, each of size  $a = =N_t$ . Inserting the completeness relation for the ferm ionic coherent states and the bosonic variables at any given time slice labeled by :

the partition function can be transform ed into:

$$= D D D D h; je^{aH} j_{+1}; ie^{x} * ;$$

$$= 0$$

where the bosonic and ferm ionic integrals are over all eld components:  $_{xx}$ ,  $_{xx}$  and  $_{xx}$  with = 0;1;  $_{t}$ ;N. In the temporal direction, periodic and anti-periodic boundary conditions are understood for the eld and , respectively.

The matrix element in the above expression can be evaluated easily using the properties of the coherent states and the fact that the tem poral lattice spacing a 0.1t is convenient to introduce a re-scaled eld  $A_x$  via:

$$A_{x} = \hat{g}^{p} \frac{2!_{0}}{2!_{0}} x ;$$
 (6)

where we have used the notation x to label the four-dimensional site (;x), and  $\hat{g}$  is the dimensionless coupling measured by t, i.e.  $\hat{g}$  g=t. Sim ilarly, we will use the notation:  $\hat{f} = =t$  and  $\hat{f}_0 = !_0=t$ . Finally, the partition function of the model is given by [13,14]:

$$= {}^{Z} DA \exp \left( {}^{X} A_{x} \frac{(\hat{\theta}_{0}^{2} + !_{0}^{2} a^{2})_{xy}}{4\hat{g}^{2}!_{0}a} A_{y} \det(M [A]^{2}) ; \right)$$

$$M [A]_{xy} = at {}^{X^{3}} ({}_{x+\hat{1}_{xy}} + {}_{x\hat{1}_{xy}}) + [1 + at(^{+} A_{x})]_{xy} {}_{x_{0} x \hat{0}_{xy}} ; (7)$$

where we have used x = (x;s) to collectively label 3 + 1 dimensional lattice sites. The sign function  $x_0 =$  is present to insure the anti-periodic boundary condition for the ferm ion elds in the temporal direction.

It is noted that the real ferm ion matrix M is not H erm itean. However, since the matrix M is real and the up and down spin electrons share the same ferm ion matrix, the electron is positive denite for any value of the chemical

potential. Therefore, this path integral representation for the Holstein model is suitable for Monte Carlo simulations [13,14] without the infamous \sign problem ".

## 3 The charge density wave phase

To perform a mean-eld analysis for the possible charge density wave long range order, we assume that the elective action:

$$S_{eff}[A_{x}] = \sum_{x,y}^{X} A_{x} \frac{(\hat{\theta}_{0}^{2} + \hat{\theta}_{0}^{2}a^{2})_{xy}}{4\hat{g}^{2}!_{0}a} A_{y} \quad 2Tr\log M[A_{x}]; \quad (8)$$

has a m in im um at the \ferrim agnetic" background eld  $A_x^{(M F)} = M + ()^{*}$ , characterized by the magnetization parameter  $\hat{M}$  and the staggered magnetization parameter  $\hat{M}$ . In this background eld, the ferm ion matrix M, which will be denoted as M <sup>(0)</sup>, has a simple block diagonal form in four-momentum space:

$$M_{pq}[A^{(MF)}] \quad M_{pq}^{(0)} = [1 e^{ip_{0}} + at(\sim \hat{p})]_{pq} + at^{(0)}_{qp+Q}; \quad (9)$$

where p and q are two four-m on enta, the tem poralcom ponents of which being the usual ferm ionic M atsubara frequencies. The parameters ~ and  $_{p}^{}$  designate  $^{+}$  M and  $_{p}$ =t, respectively, and Q equals (0; ; ; ). A swe will show shortly, a non-vanishing staggered m agnetization order parameter ^ signals a CDW phase in the system while the value of M represents the \renorm alization e ect" of the chem ical potential.

W e decompose the scalar eld  $A_x$  as:

$$A_x = A_x^{(M F)} + A_x = M + (N^{*} + A_x ;$$

and expand the e ective action (8) around the mean-eld solution  $A_x^{(MF)}$ . The fact that  $A_x^{(MF)}$  being a saddle point of the e ective action insures that the term linear in  $A_x$  is absent in this expansion. Therefore, to second order in  $A_x$ , we obtain:

$$S_{eff} [A] = S_{eff}^{(0)} [A^{(MF)}] + S_{eff}^{(2)} [A];$$

$$S_{eff}^{(0)} [A^{(MF)}] = \frac{!_{0}a(M^{2} + {}^{2})}{4\hat{g}^{2}} \qquad 2TrlogM [A^{(MF)}];$$

$$S_{eff}^{(2)} [A_{x}] = Tr M^{(0) 1} M M^{(0) 1} M : \qquad (10)$$

This serves as our starting point for the mean-eld calculation. In this paper, only the lowest order mean-eld results will be studied. These results are contained in  $S_{eff}^{(0)}$ .

Since the mean-eld ferm ion matrix M  $^{(0)}$  only couples momentum p with momentum p+Q, the lowest order elective action S  $^{(0)}$  log  $^{(0)}$  can be easily obtained:

$$S_{eff}^{(0)} [\mathbb{A}^{(M|F|)}] = \frac{!_{0}a[\mathbb{M}^{2} + \mathbb{A}^{2}]}{4\hat{g}^{2}}$$

$$X_{p} \log 1 + at \sim e^{ip_{0}^{2}} at^{2}t^{2}t_{p}^{2}; \qquad (11)$$

where we have introduced the energy spectrum in the CDW phase:

$$\hat{\mathbf{E}}_{p}^{2} = \gamma_{p}^{2} + \gamma_{p}^{2} : \qquad (12)$$

We therefore see that, if a non-zero solution for the order parameter ^exists, the energy spectrum develops an energy gap characterized by ^.

It turns out that the sum m ation over the tem poral component  $p_0$  in eq. (11) can be performed analytically. Therefore, we obtain:

$$S_{eff}^{(0)} = \frac{!_{0}a(M^{2} + ^{2})}{4\hat{g}^{2}}$$

$$X_{p} \log 1 + 1 + at(\sim \hat{E_{p}})^{N_{t}} 1 + 1 + at(\sim + \hat{E_{p}})^{N_{t}} : (13)$$

In most cases, one is only concerned with the so-called continuum limit: a ! 0 with  $N_t a = being xed$ . Then,

$$1 + at(~ + \hat{E_p})^{N_t} exp t(~ + \hat{E_p})$$
:

The free energy per lattice site: f  $\log = (V_3)$ , apart from irrelevant constant term s, is thus obtained <sup>2</sup> to the lowest order in mean-eld theory in the continuum limit:

$$f^{(0)} = \frac{!_0}{4\hat{g}^2} (\hat{M}^2 + \hat{\gamma}^2) - \frac{1}{V_3} \int_{p}^{X} \log[\cosh(t_{\gamma}) + \cosh(t_p^2)] : (14)$$

 $<sup>^2</sup>$  W e use V<sub>3</sub> to designate the num ber of sites of the three dimensional lattice.

The chem ical potential is related to the total electron number via:  $hN i = 0 \log = (0)$ . Using the doping fraction  $x = hN i=V_3$  1 and taking the continuum limit, this equation reads:

$$x = \frac{1}{V_{3}} \frac{x}{p} \frac{\sinh(t^{-})}{\cosh(t^{-}) + \cosh(t^{-})} :$$
(15)

It is seen that the solution  $\sim$  will have the same sign as x, in particular, at half-lling (x = 0), the solution to Eq. (15) is:  $\sim$  = 0.

The requirement that the background eld  $A_x^{MF}$  being a minimum of the elditor can be utilized to derive the so-called gap equations. The equation for  $\hat{M}$  yields the solution:

$$\hat{M} = 2(1 + x)\hat{g}^2 = \hat{f}_0$$
; (16)

where 1 + x is given by eq. (15) , while the equation for  $^{2}$  in the continuum lim it reads:

$$\frac{\hat{r}_0}{2\hat{q}^2} = \frac{1}{V_3} \frac{X}{p} \frac{\sinh(\vec{t}\hat{E}_p) = \hat{E}_p}{\cosh(\vec{t} - ) + \cosh(\vec{t}\hat{E}_p)} ; \qquad (17)$$

At a given doping level x, one needs to use both Eq. (15) and Eq. (17) to solve for ~ and  $\hat{}$ . The critical temperature T<sub>c</sub> = 1=  $_{c}$  for the CDW phase is obtained from Eq. (17) and Eq. (15) by setting the order parameter  $\hat{}$  to zero, or equivalently, by setting E<sub>p</sub> =  $_{p}$  for a given value of x:

$$\frac{\hat{r}_{0}}{2\hat{g}^{2}} = \frac{1}{V_{3}} \frac{X}{p} \frac{\sinh(c_{c}t_{p}^{*}) = \hat{r}_{p}}{\cosh(c_{c}t_{p}^{*}) + \cosh(c_{c}t_{p}^{*})} ; \qquad (18)$$

It is also instructive to calculate the ensemble average of the local electron number operator  $n_x \qquad c_x^y \ c_x$ . To lowest order in mean-eld theory, it is given by:

$$hn_x i = 2 + 2hM_{0,x;0+1,x}^{(0)1} i$$
:

Keeping a nite and after som e algebra, one obtains:

$$hn_{x}i = \frac{hNi}{V_{3}} + (j'\frac{r_{0}}{2g^{2}} + 0) (a) = \frac{r_{0}}{2g^{2}}h' + (j'^{1} + 0) (a); \quad (19)$$

A swe claim ed before, a non-vanishing order parameter ^ opens up an energy gap in the spectrum and signals a charge density wave order in the system.

A nother useful quantity to characterize the CDW phase transition is the CDW susceptibility  $_{CDW}$  de ned by:

$$_{CDW} = \frac{a}{V_3} X_{x_{i}y_i} ( )^{x_y} \ln_{\mu x} n_{0_{i}y} i :$$
 (20)

By virtue of translational invariance, one obtains:

$$_{CDW} = \frac{1}{N_{t}} \sum_{x,y}^{X} e^{iQ(x y)} h (x) (y)i$$
:

Since the ferm ion propagator for up and down spins are identical, we have:

$$_{CDW} = \frac{2}{N_{t}} \sum_{x,y}^{X} e^{iQ(x y)} h(x) (y) (y) i :$$
 (21)

This expression can be represented in momentum space by a loop diagram. We will calculate the susceptibility in the phase where = 0 for simplicity. To lowest order in mean-eld theory, the susceptibility is given by:

where we have used the fact that:  $\hat{p} = \hat{p}_{p+Q}$ . Using similar techniques as before, the sum m ation over  $p_0$  can be performed analytically, and in the continuum limit, the above equation is reduced to:

$${}^{(0)}_{CDW} = \frac{1}{V_3} \frac{X}{p} - \frac{1}{p} \frac{1}{\cosh(t^{-}) + \cosh(t^{-})} : \qquad (23)$$

A better approximation, the Random Phase Approximation (RPA), for the CDW susceptibility can be obtained by summing over a geometric series of  $^{(0)}_{C}$  with one phonon exchange. In this approximation, the CDW susceptibility becomes:

$${}^{(RPA)}_{CDW} = \frac{{}^{(0)}_{CDW}}{1 (2 tg^2 = !_0)} ; \qquad (24)$$

which becomes divergent exactly at the critical temperature  $T_c$ , as is evident by comparing with Eq. (18).

### 4 The superconducting phase transition

In the previous section, we have discussed the possibility of the CDW phase transition in the Holstein model. This phase transition is characterized by a long range order parameter which is diagonal in electron spins. It turns out that the system also permits a phase with long range order which is o - diagonal in the space of the electron spins. This phase is the conventional BCS-type superconducting phase with Cooper pairing. To see such a phase transition, the phonon eld is integrated out from the path integral representation of the partition function. Then, another set of boson elds, namely a real scalar eld  $_x$ , a complex scalar eld  $_x$  and its complex conjugate  $_x$ , are integrated in. Introducing the four component ferm ion eld notation:

$$\begin{array}{c} 0 & 1 \\ 1x & C \\ x = \begin{array}{c} B \\ B \\ C \\ 0 \end{array} \begin{array}{c} 1x \\ 2x \\ 1x \\ 2x \end{array} \begin{array}{c} 2x \\ 2x \end{array} \begin{array}{c} (25) \end{array}$$

the action of the model can be written as:

$$S = \frac{1}{2} \times D[; ] \times; y \quad y$$
  
+  $\frac{!_{0}a}{2\dot{q}^{2}} \times j_{x}j_{x}^{2} + x \frac{\dot{\theta}_{0}^{2} + !_{0}^{2}a^{2}}{4\dot{q}^{2}!_{0}a} |_{xy} \quad y :$  (26)

where the index and run from 1 to 4 and the anti-symmetric fermion matrix D [; ]  $_{x;y}$  is given by:

where the matrix M  $_{xy}^{(0)}$  is given by:

$$M_{xy}^{(0)} = at_{i=1}^{X^{3}} (x_{x+\hat{i}_{y}} + x_{x+\hat{i}_{y}}) + (1 + at^{*})_{xy} x_{0} x_{0} \hat{i}_{y} :$$
(28)

The e ective action of the system is obtained by integrating out the ferm ion elds, resulting in the Pfa an (the square root of the determ inant) of the

corresponding ferm ion matrix D [; ]:

$$S_{eff} = \frac{!_{0}a^{X}}{2g^{2}} j_{x} j_{x} j_{x} j_{x} + j_{x} \frac{(a_{0}^{2} + !_{0}^{2}a^{2})}{4g^{2}!_{0}a} j_{xy} \frac{1}{2} \operatorname{Tr} \log D[;]: (29)$$

We now proceed to search for a constant mean-eld solution of the type:  $_{x} = \hat{}_{BCS}$  and  $_{x} = _{0}$  which m inim izes the electric action. In this case, the ferm ion matrix D is diagonal in four-momentum space, i.e.  $D_{pq} = D^{(0)}$  (p)  $_{pq}$ and it is given by:

$$D^{(0)}(p) = \begin{cases} 0 & at_{BCS} & M^{(0)}(p) & 0 \\ \frac{at_{BCS}}{M} & \frac{0}{(0)}(p) & 0 & 0 \\ 0 & M^{(0)}(p) & 0 & 0 & at_{BCS} & A \\ 0 & M^{(0)}(p) & at_{BCS} & 0 \end{cases} ; (30)$$

with M  $^{(0)}(p) = 1 + at(^{p}) e^{ip_{0}}$ . Therefore, to low est order in m ean-eld theory, the electric action is found to be:

$$\frac{1}{-}S_{eff}^{(0)} = \frac{!_{0}a}{2\dot{g}^{2}}j_{BCS}^{2}j + \frac{!_{0}a}{4\dot{g}^{2}} \frac{2}{0}$$
$$\frac{1}{-}\sum_{p}^{X}\log_{p}^{h}j = e^{ip_{0}} + at(^{n}_{p})j + (at)^{2}j_{BCS}^{n}j : (31)$$

Since the ferm ion contribution is independent of  $_0$ , it is im mediately seen that the solution for  $_0$  is  $_0 = 0$ . The sum mation over M atsubara frequencies can be performed analytically. In the continuum limit the result is:

$$\frac{1}{2}S_{eff}^{(0)} = \frac{!_{0}a}{2g^{2}}j_{BCS}^{2}j_{N_{t}}^{2} \qquad \frac{1}{N_{t}} \qquad \frac{1}{p} \log 2 + e^{E_{p}} + e^{E_{p}} ; \quad (32)$$

where the spectrum  $E_p$  is given by:

$$E_{p} = \frac{q}{(p)^{2} + t^{2} \frac{2}{BCS}} :$$
 (33)

Chemical potential is determined from band lling. Using the doping fraction parameter x, the chemical potential satis as the following equation:

$$x = \frac{1}{V_3} \frac{x}{p} - \frac{p}{E_p} \tanh \frac{E_p}{2}$$
 : (34)

It is noted that, at half-lling x = 0 and the solution is = 0 due to the symmetry of p. The superconducting energy gap  $^{n}_{BCS}$  is obtained from the

famous BCS gap equation:

$$\frac{1}{g^2} = \frac{1}{V_3} \frac{X}{p} + \frac{t}{E_p} \frac{1}{t} \tanh \frac{E_p}{2} :$$
(35)

The critical tem perature for the superconducting phase transition is obtained by setting the BCS gap parameter  $\hat{P}_{BCS}$  to zero in the above equation:

$$\frac{\uparrow_0}{g^2} = \frac{1}{V_3} \frac{X}{p} \frac{t}{j} \frac{t}{pj} \tanh \frac{cj}{2} \frac{pj}{2} : \qquad (36)$$

The ferm ion propagator is given by the inverse matrix of D which again is diagonal in momentum space. If we denote:

$$h_{x} = \frac{1}{p} e^{ip(x y)} \mathbb{D}^{(0)} [1 (p) ; \qquad (37)$$

then the matrix  $[D^{(0)}]^1$  (p) is given by:

$$\mathbb{D}^{(0)}]^{1}(\mathbf{p}) = \frac{1}{D(\mathbf{p})} \begin{bmatrix} 0 & at_{BCS}^{*} & M^{(0)}(\mathbf{p}) & 0 \\ \frac{at_{BCS}^{*} & 0 & 0 & M^{(0)}(\mathbf{p}) \\ M^{(0)}(\mathbf{p}) & 0 & 0 & at_{BCS}^{*} \\ 0 & M^{(0)}(\mathbf{p}) & at_{BCS}^{*} & 0 \end{bmatrix}$$
(38)

with D (p) =  $M^{(0)}(p)f + jat_{BCS}f$ .

W e can also calculate the superconducting susceptibility de ned by:

$$_{BCS} = \frac{1}{N_{t}} \sum_{x,y}^{X} h_{1x} \sum_{2x} A_{y} \sum_{3y} i:$$
(39)

For simplicity, we will evaluate the superconducting susceptibility in the phase with vanishing  $\hat{B}_{BCS}$  (high tem perature phase). A fler som e algebra, we obtain to the lowest order:

$${}^{(0)}_{BCS} = \frac{1}{V_3} \frac{X}{p} \frac{1}{j p^{j}} \tanh \frac{j p^{j}}{2} :$$
(40)

Under RPA, the susceptibility becomes:

$${}^{(RPA)}_{BCS} = \frac{{}^{(0)}_{BCS}}{1 \quad (t_{0}^{0}=t_{0}^{0})} ; \qquad (41)$$

which becom es divergent exactly at  $_{\rm c}$  determ ined by Eq. (36).

## 5 Results and discussions

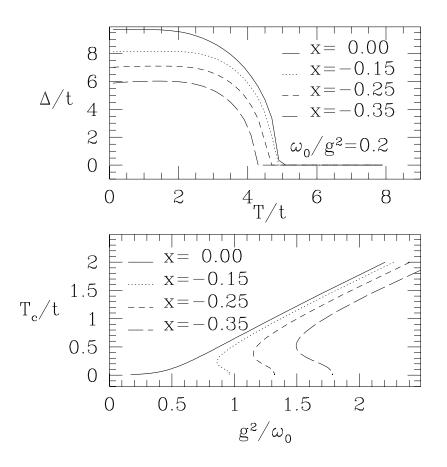


Fig. 1. In the lower half of the gure, the critical temperatures for the CDW phase transition are plotted as a function of  $g^2=!_0$  for four di erent doping levels: x = 0.00; 0:15; 0:25; 0:35. In the upper half of the gure, the order parameters for the CDW phase transition are plotted as a function of the temperature T=t for a given value of  $!_0=g^2 = 0.2$  for four di erent doping levels: x = 0.0; 0:15; 0:25; 0:35.

M ean-eld equations discussed in previous sections can be evaluated num erically and the results for the critical temperatures and the order parameters are summarized in Fig. 1 and Fig. 2. In the lower half of the gures, we plot the critical temperatures as a function of  $g^2 = {}^0$  for four dimension doping levels: x = 0.00; 0.15; 0.25; 0.35. The critical temperatures for the superconducting phase transition are represented by the four lines that increase with  $g^2 = {}^0$ near the bottom of Fig. 2. They show rather weak dependence on doping. The corresponding lines for the CDW phase transition illustrate a much stronger

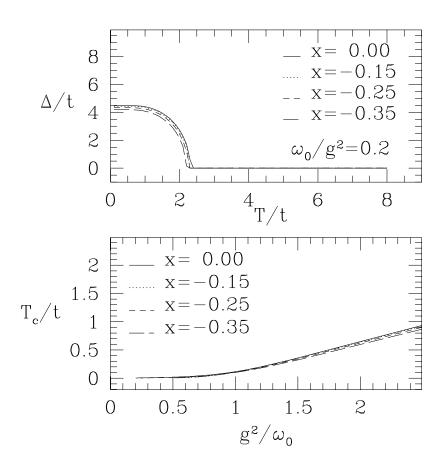


Fig. 2. In the lower half of the gure, the critical tem peratures for the BCS superconducting phase transition are plotted as a function of  $g^2=!_0$  for four di erent doping levels: x = 0.00; 0.15; 0.25; 0.35. In the upper half of the gure, the order parameters for the BCS superconducting phase transition are plotted as a function of the tem perature T=t for a given value of  $!_0=g^2 = 0.2$  for four di erent doping levels: x = 0.0; 0.15; 0.25; 0.35.

dependence on doping com pared to the superconducting critical tem peratures. It is noted that, for a given value of  $\hat{g}^2 = \hat{f}_0$ , the critical tem peratures for the CDW phase transition decrease as the doping is increased. At exactly half lling, the critical tem perature for the CDW phase transition is always higher than that of the superconducting phase transition. While the issue of the stability of the CDW and superconducting phases can only be addressed by a more sophisticated calculation, here we simply take the magnitude of the critical tem peratures and order parameters as a measure of the tendency that the system is likely to be in one of these phases. Thus, we expect the system to be in a CDW phase transition eventually becomes smaller than that of the superconducting phase transition. This is a signal that the CDW phase will eventually becom es unstable when the system is doped away from half lling. The superconducting phase will becom e dom inant at low tem peratures.

In the upper half of the gures, we plot the order parameters  $\hat{} = \pm for the CDW and the superconducting phase transitions as a function of tem perature <math>T = tat ?_0 = \hat{g}^2 = 0.2$  for the same four dierent doping levels. It is seen that, for a given value of ?\_0 = \hat{g}^2, both order parameters decrease as the doping is increased. However, the order parameter for the CDW phase decreases much more rapidly than the superconducting order parameter when the system moves away from half lling. These features indicate that the CDW phase is most favored at half lling, in agreement with our qualitative expectations discussed in the introduction.

### 6 Conclusions

In this paper, we present ourm ean-eld analysis of the three dimensional Holstein model. A path integral representation of the model is obtained which is suitable for further M onte Carlo simulations. The critical temperatures and the order parameters are obtained within mean-eld approximation for both the CDW phase and BCS superconducting phase transitions. Our results are consistent with the picture that the CDW phase is most favored at half-lling. A way from half lling, the usual BCS superconducting phase becomes im portant. Higher order calculations are necessary to further explore the competition between di erent electronic phase transitions.

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